

20 V, complementary N/P-channel Trench MOSFET 30 June 2015 Product

Product data sheet

1. General description

Complementary N/P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Very low threshold voltage for portable applications: $V_{GS(th)} = 0.7 V$
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- ElectroStatic Discharge (ESD) protection > 1 kV HBM

3. Applications

- Relay driver
- High-speed line driver
- Level shifter
- Power management in battery-driven portables

4. Quick reference data

Table 1. Qu	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
TR1 (N-chani	nel), Static characteristic	S					
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 600 mA; T _j = 25 °C		-	470	620	mΩ
TR2 (P-chann	nel), Static characteristic	S		÷			
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -500 mA; T _j = 25 °C		-	1.02	1.4	Ω
TR1 (N-chani	nel)	·					,
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	-	600	mA
TR2 (P-chani	nel)	·					,
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-	-500	mA

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- Table 2. **Pinning information** Pin Symbol Description **Simplified outline Graphic symbol** 1 S1 source TR1 D1 D2 1 6 2 G1 gate TR1 7 Λ drain TR2 3 D2 G1 2 5 G2 V 4 S2 source TR2 8 R 3 4 gate TR2 5 G2 S1 S2 6 D1 drain TR1 017aaa262 Transparent top view D1 drain TR1 7 DFN1010B-6 (SOT1216) 8 D2 drain TR2
- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².

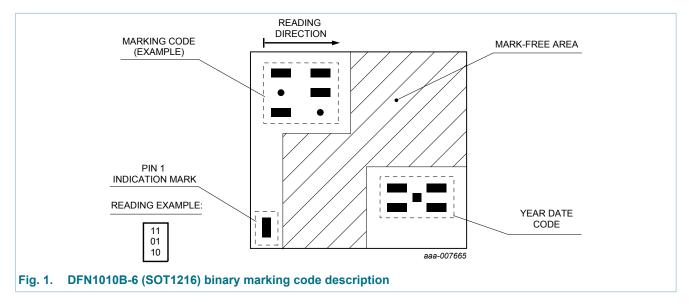
5. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMCXB900UE	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216				

6. Marking

Table 4. Marking codes

Type number	Marking code
PMCXB900UE	10 00 00



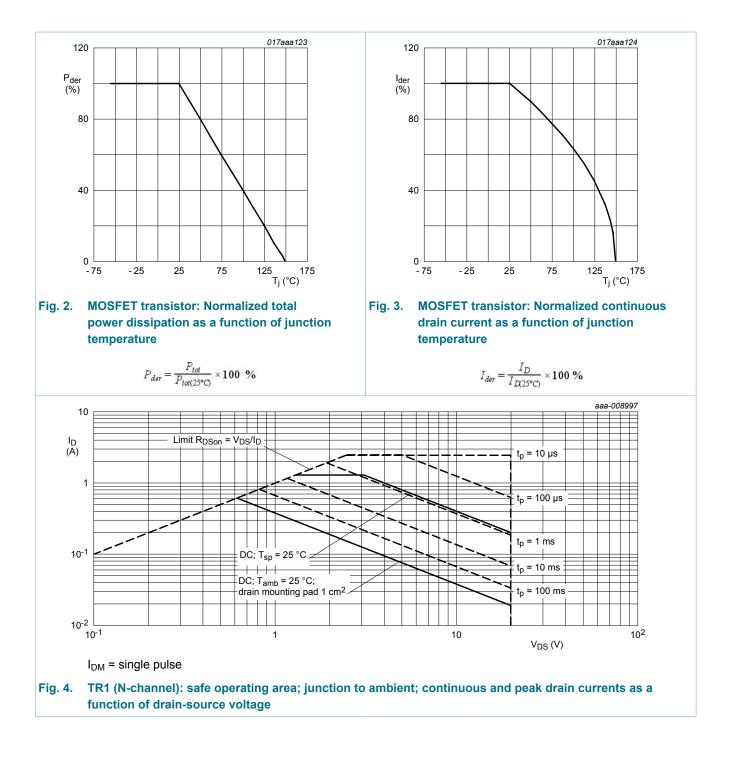
Limiting values 7.

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

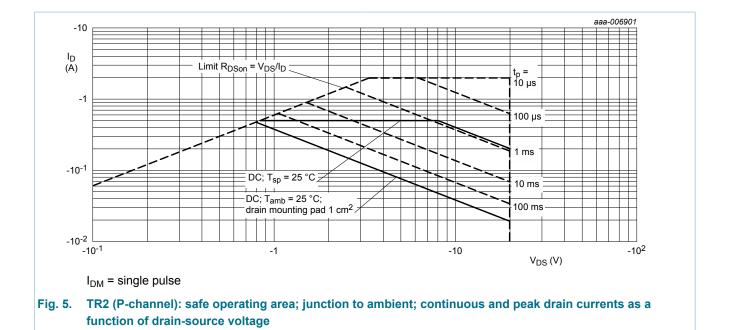
Symbol	Parameter	Conditions		Min	Max	Unit
TR1 (N-cha	nnel)					_
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C	[1]	-	600	mA
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	400	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	2.5	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	265	mW
			[1]	-	380	mW
		T _{sp} = 25 °C		-	4025	mW
TR1 (N-cha	nnel), Source-drain diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	400	mA
TR2 (P-cha	nnel)			·		
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	[1]	-	-500	mA
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-300	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-2	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	265	mW
			[1]	-	380	mW
		T _{sp} = 25 °C		-	4025	mW
TR2 (P-cha	nnel), Source-drain diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	-350	mA
Per device					1	
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

 Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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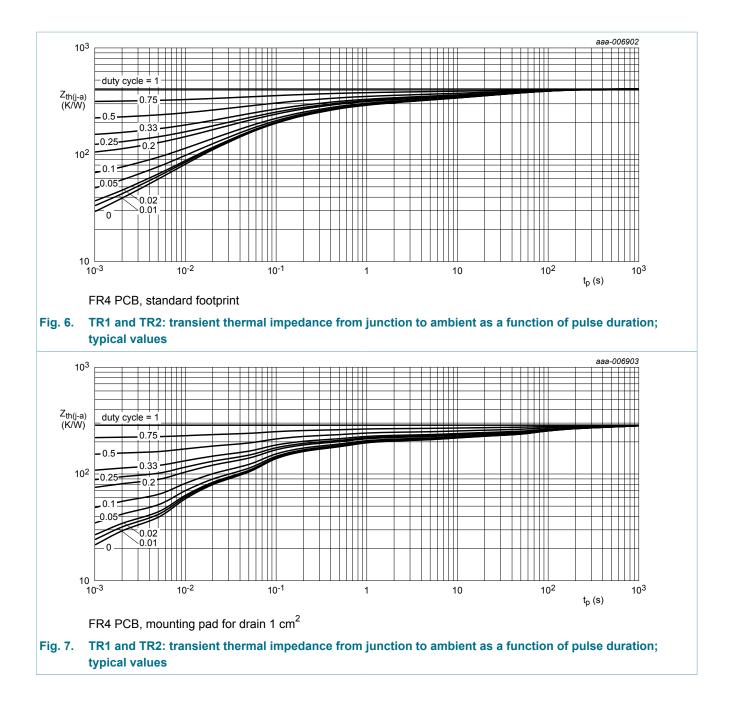
8. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
TR1 (N-cha	innel)						,
R _{th(j-a)}	thermal resistance	in free air	[1]	-	410	475	K/W
	from junction to ambient		[2]	-	285	330	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	27	31	K/W
TR2 (P-cha	nnel)	1					
R _{th(j-a)}	thermal resistance	in free air	[1]	-	410	475	K/W
	from junction to ambient		[2]	-	285	330	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	27	31	K/W

[1] Device mounted on an FR4 PCB, single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 1 cm².





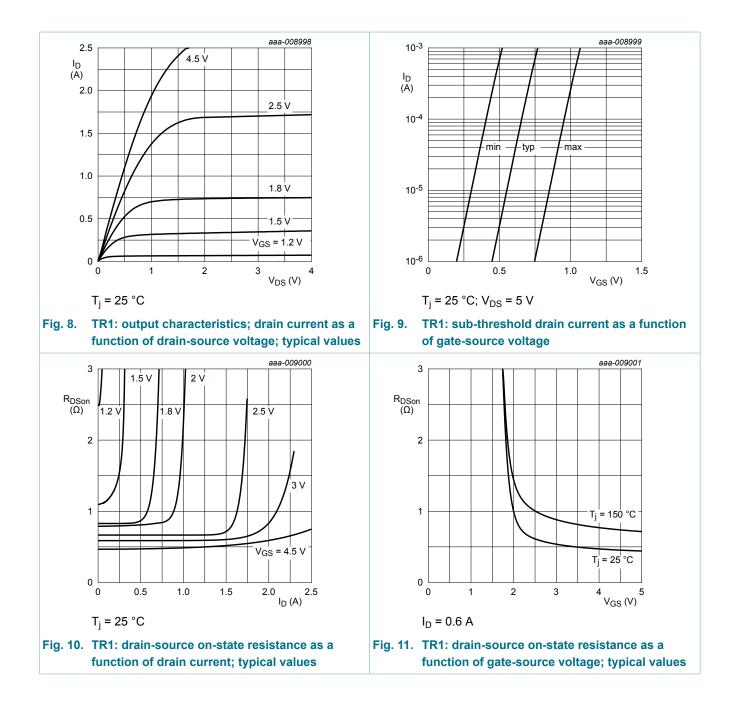
9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TR1 (N-cha	nnel), Static characteristic	is in the second s				
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.45	0.7	0.95	V
I _{DSS}	drain leakage current	V_{DS} = 20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
R _{DSon}	drain-source on-state	V_{GS} = 4.5 V; I _D = 600 mA; T _j = 25 °C	-	470	620	mΩ
	resistance	V_{GS} = 4.5 V; I _D = 600 mA; T _j = 150 °C	-	760	1000	mΩ
		V_{GS} = 2.5 V; I _D = 500 mA; T _j = 25 °C	-	620	850	mΩ
		V _{GS} = 1.8 V; I _D = 100 mA; T _j = 25 °C	-	845	1300	mΩ
		V _{GS} = 1.5 V; I _D = 10 mA; T _j = 25 °C	-	1125	3000	mΩ
		V_{GS} = 1.2 V; I _D = 1 mA; T _j = 25 °C	-	2210	-	mΩ
9 _{fs}	transfer conductance	V_{DS} = 5 V; I _D = 600 mA; T _j = 25 °C	-	1	-	S
TR1 (N-cha	nnel), Dynamic characteri	stics				
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 600 mA; V _{GS} = 4.5 V;	-	0.4	0.7	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.1	-	nC
Q _{GD}	gate-drain charge		-	0.1	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; f = 1 MHz; V _{GS} = 0 V;	-	21.3	-	pF
C _{oss}	output capacitance	$T_j = 25 °C$	-	5.4	-	pF
C _{rss}	reverse transfer capacitance		-	4.2	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; I _D = 600 mA; V _{GS} = 4.5 V;	-	5.6	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	9.2	-	ns
t _{d(off)}	turn-off delay time		-	19	-	ns
t _f	fall time		-	51	-	ns
TR1 (N-cha	nnel), Source-drain diode	characteristics	1	1		
V _{SD}	source-drain voltage	I _S = 360 mA; V _{GS} = 0 V; T _i = 25 °C	-	0.8	1.2	V

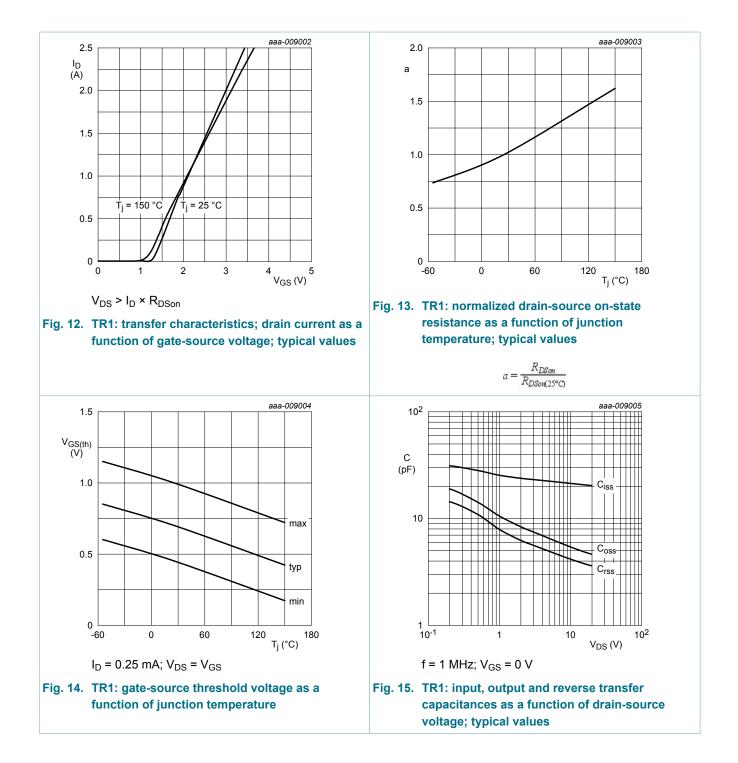
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
TR2 (P-cha	nnel), Static characteristic	S				
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -500 mA; T _j = 25 °C	-	1.02	1.4	Ω
	resistance	V_{GS} = -4.5 V; I _D = -500 mA; T _j = 150 °C	-	1.54	2.1	Ω
		V_{GS} = -2.5 V; I _D = -200 mA; T _j = 25 °C	-	1.27	2.2	Ω
		V_{GS} = -1.8 V; I _D = -40 mA; T _j = 25 °C	-	1.7	3.3	Ω
		V_{GS} = -1.5 V; I _D = -10 mA; T _j = 25 °C	-	2.3	5	Ω
		V _{GS} = -1.2 V; I _D = -1 mA; T _j = 25 °C	-	3.5	-	Ω
9 _{fs}	transfer conductance	V_{DS} = -10 V; I _D = -500 mA; T _j = 25 °C	-	480	-	mS
TR2 (P-cha	nnel), Dynamic characteris	stics	I			
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -450 mA;	-	1.19	2.1	nC
Q _{GS}	gate-source charge	V _{GS} = -4.5 V; T _j = 25 °C	-	0.17	-	nC
Q _{GD}	gate-drain charge		-	0.1	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	43	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	14	-	pF
C _{rss}	reverse transfer capacitance		-	8	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = -10 V; I _D = -450 mA;	-	2.3	-	ns
t _r	rise time	V _{GS} = -4.5 V; R _{G(ext)} = 6 Ω; T _j = 25 °C	-	5	-	ns
t _{d(off)}	turn-off delay time		-	13.5	-	ns
t _f	fall time		-	6	-	ns
TR2 (P-cha	nnel), Source-drain diode	characteristics		_		
V _{SD}	source-drain voltage	I _S = -115 mA; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

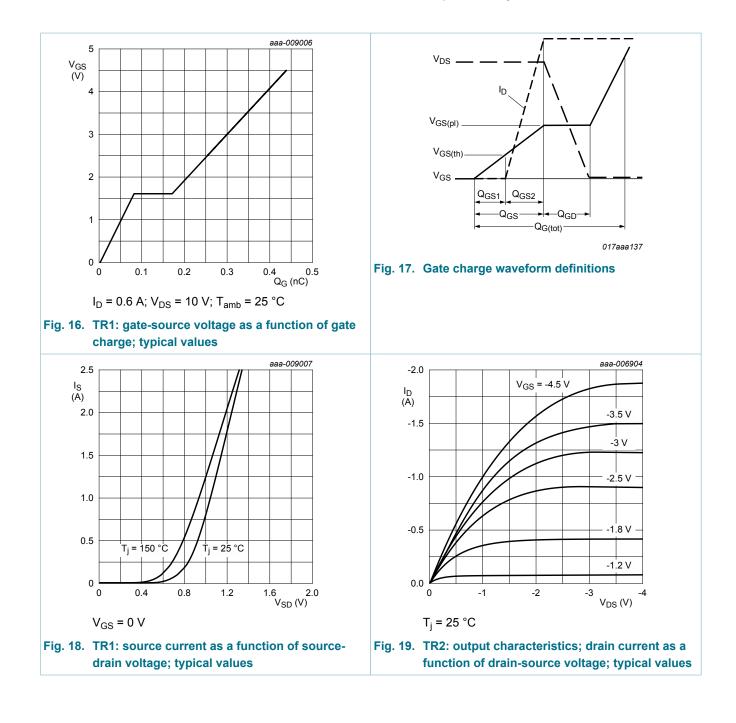
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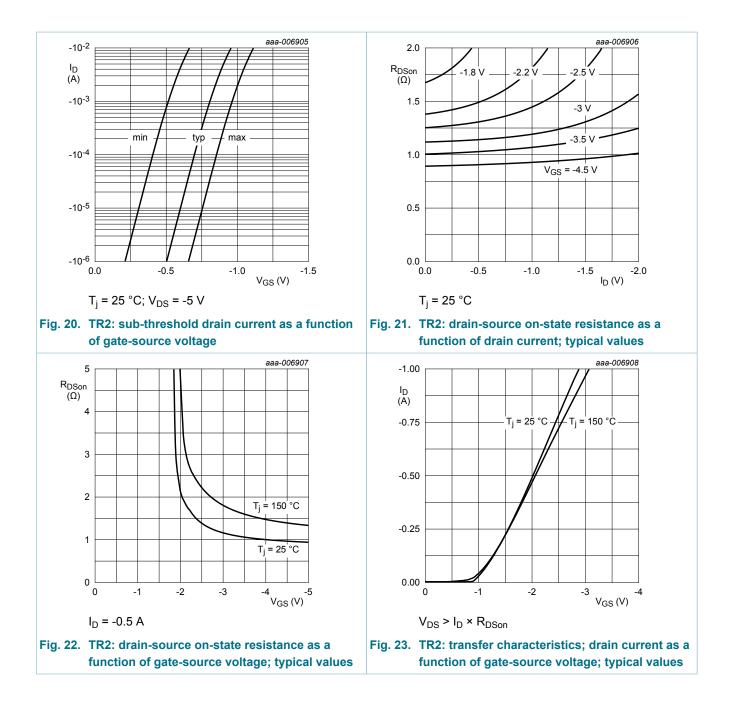
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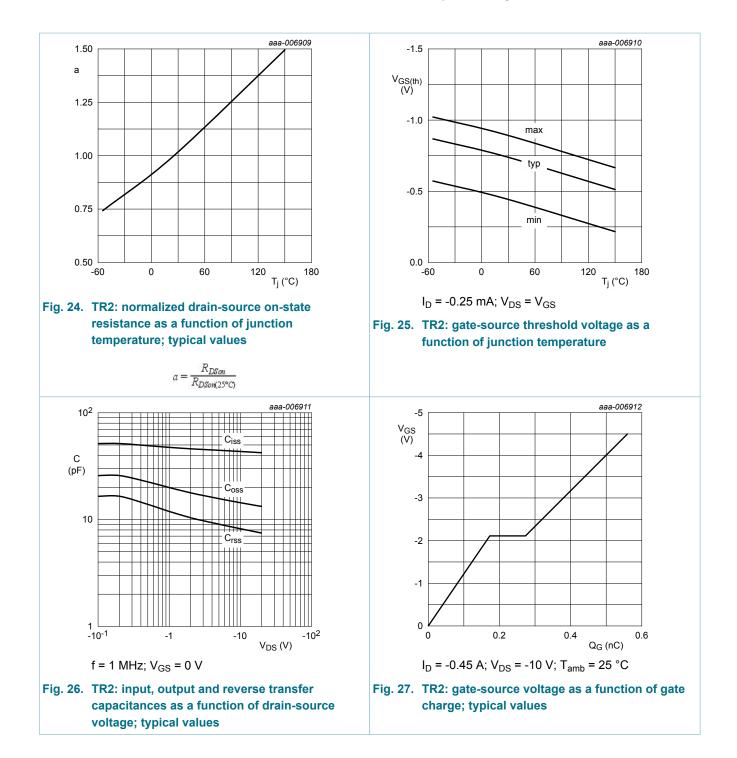


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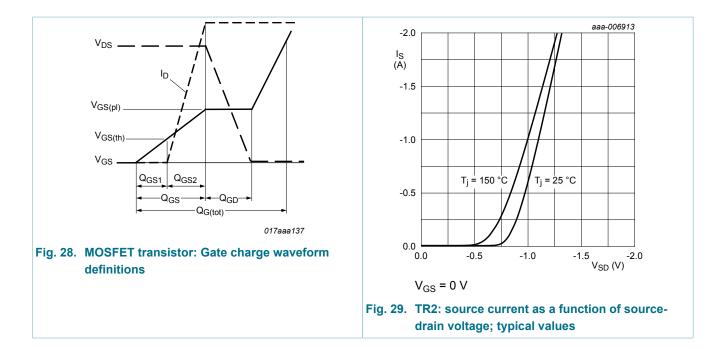
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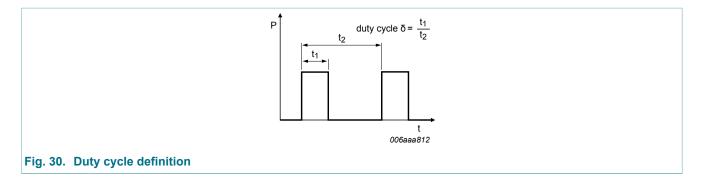


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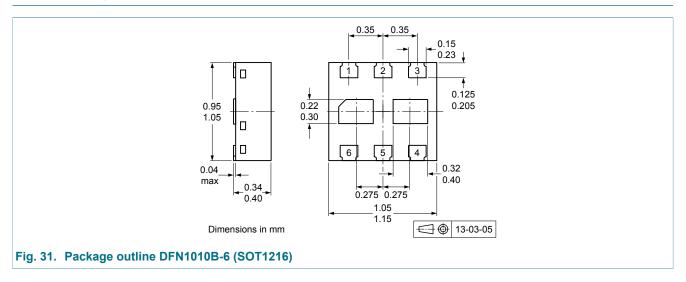
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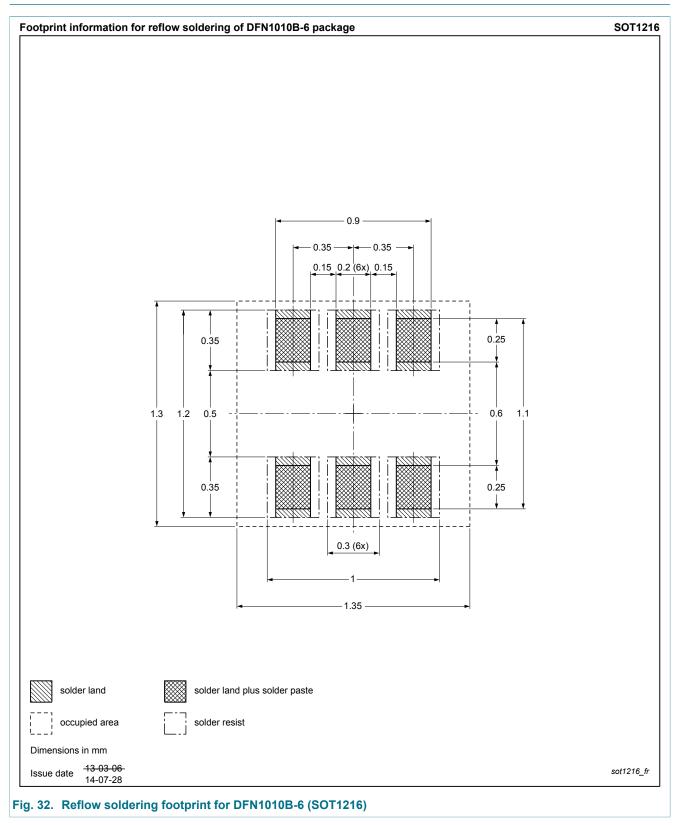
10. Test information



11. Package outline



12. Soldering



13. Revision history

Table 8. Revision hi	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMCXB900UE v.2	20150630	Product data sheet	-	PMCXB900UE v.1
Modification:	Change of binary m	arking code position.		,
PMCXB900UE v.1	20131007	Product data sheet	-	-

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14. Legal information

14.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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